# SMCJ33 SMCJ33C Bidirectional Transient Voltage Suppressor TVS SMCJ33CA Diode DO-214AB

#### **Basic Information**

• Place of Origin: Shenzhen, Guangdong, China

• Brand Name: SOCAY

• Certification: UL,REACH,RoHS,ISO

Model Number: SMCJ33CA
Minimum Order Quantity: 3000PCS
Price: Negotiable
Packaging Details: tape reel
Delivery Time: 5-8 work days
Supply Ability: 10000000pcs



### **Product Specification**

SMCJ33CA Name: TVS DiodesSMCJ33CA Package Type: DO-214AB/SMC

SMCJ33CA Vrwm: 33V
 Vbr@lt (Min.): 36.7V
 Vbr@lt (Max.): 40.60V
 SMCJ33CA It: 1mA
 SMCJ33CA Vc@lpp: 53.3V
 Storage Temperature -55 To +150

Storage Temper Range:

#### **Product Description**

## SMCJ33 SMCJ33C Electronic Component Bidirectional Transient Voltage Suppressor SMCJ Series TVS SMCJ33CA Diode DO-214AB

DATASHEET: SMCJ v2107.1.pdf

#### SMCJ Series TVS SMCJ33CA Illustration:

The SMCJ Series TVS SMCJ33CA is designed specifically to protect sensitive electronic equipment from voltage transients induced by lightning and other transient voltage events.

#### SMCJ Series TVS SMCJ33CA Features:

- u TVS SMCJ33CA is For surface mounted applications in order to optimize board space
- u It has Low leakage
- u It is a Bidirectional unit
- u Glass passivated junction
- u TVS SMCJ33CA has Low inductance
- u Excellent clamping capability
- u 1500W Peak power capability at 10 × 1000µs waveform Repetition rate (duty cycle):0.01%

TVS Part	Number	TVS Markir		IVS Reverse	TVS Breakdo Voltage (V) @IT	VBR	Test Current	Clamping Voltage VC @IPP	Peak Pulse	Maximum Reverse Leakage IR @VRWM (µA)
Uni	Bi	Uni	Bi		MIN	MAX				
la	IA	GFK	BFK	I	33.30	36.80	1	48.4	30.99	5
SMCJ33 A	SMCJ33C A	GFM	BFM	33.0	36.70	40.60	1	53.3	28.14	5

#### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted) Voltage V<sub>BR</sub> (V) Marking MIN MAX SMCJ5.0A SMCJ5.0CA GDE BDE 5.0 7.00 163.04 1000 6.40 10 9.2 SMCJ6.0A SMCJ6.0CA GDG BDG 6.0 6.67 7.37 10 10.3 145.63 1000 SMCJ6.5A 7.22 10 500 SMCJ6.5CA GDK 7.98 SMCJ7.0A SMCJ7.0CA GDM BDM 7.0 7.78 10 12.0 125.00 200 SMCJ7.5A SMCJ7.5CA GDP BDP 8.33 9.21 12.9 116.28 100 SMCJ8.0A SMCJ8.0CA GDR BDR 8.0 8.89 9.83 13.6 110.29 50 1 SMCJ8.5A SMCJ8.5CA GDT BDT 8.5 9.44 10.40 14.4 104.17 20 SMCJ9.0A SMCJ9.0CA 9.0 10.00 11.10 15.4 97.40 10 SMCJ10A SMCJ10CA BDX 10.0 11.10 12.30 1 17.0 88.24 5 GDX SMCJ11A SMCJ11CA GDZ BDZ 11.0 12.20 13.50 18.2 82.42 5 SMCJ12A SMCJ12CA GEE BEE 12.0 13.30 14.70 1 19.9 75.38 5 SMCJ13A SMCJ13CA GEG BEG 13.0 14.40 15.90 21.5 69.77 SMCJ14A SMCJ14CA GEK 14.0 15.60 17.20 23.2 64.66 BEK 5 SMCJ15CA 15.0 18.50 SMCJ16A SMCJ16CA 17.80 19.70 SMCJ17A SMCJ17CA 17.0 18.90 27.6 54.35 1 SMCJ18A SMCJ18CA GET BET 18.0 20.00 22.10 29.2 51.37 5 SMCJ19A SMCJ19CA 19.0 21.10 23.30 30.8 48.73 5 GEB BEB SMCJ20A SMCJ20CA GEV BEV 20.0 22.20 24.50 32.4 46.30 SMCJ22A SMCJ22CA GEX BEX 22.0 24.40 26.90 35.5 42.25 5 SMCJ24A SMCJ24CA GF7 BEZ 24.0 26.70 29.50 1 38.9 38.56 5 SMCJ26A SMCJ26CA GFE BFE 26.0 28.90 31.90 42.1 35.63 5 33.04 SMCJ28A SMCJ28CA GFG BFG 28.0 31.10 34.40 1 45.4 5 SMCJ30CA GFK BFK 30.0 33.30 36.80 48.4 30.99 SMCJ30A BFM 36.70 53.3 28.14 SMCJ36CA 36.0 40.00 44.20 58.1 25.82 5 SMC-J40A SMCJ40CA GFR BFR 40.0 44 40 49 10 64.5 23 26 SMCJ43A SMCJ43CA GFT BFT 43.0 47.80 52.80 1 69.4 21.61

Part Number		Marking		Reverse Stand-Off Voltage	Breakdown Voltage V <sub>BR</sub> (V) @l <sub>T</sub>		Test Current	Maximum Clamping Voltage	Maximum Peak Pulse Current	Maximum Reverse Leakage I <sub>R</sub>
Uni	Bi	Uni	Bi	V <sub>RWM</sub> (V)	MIN	MAX	(mA)	V <sub>c</sub> @len (V)	Irr (A)	@V <sub>RWM</sub> (μΑ)
SMCJ45A	SMCJ45CA	GFV	BFV	45.0	50.00	55.30	1	72.7	20.63	5
SMCJ48A	SMCJ48CA	GFX	BFX	48.0	53.30	58.90	1	77.4	19.38	5
SMCJ51A	SMCJ51CA	GFZ	BFZ	51.0	56.70	62.70	1	82.4	18.20	5
SMCJ54A	SMCJ54CA	GGE	BGE	54.0	60.00	66.30	1	87.1	17.22	5
SMCJ58A	SMCJ58CA	GGG	BGG	58.0	64.40	71.20	1	93.6	16.03	5
SMCJ60A	SMCJ60CA	GGK	BGK	60.0	66.70	73.70	1	96.8	15.50	5
SMCJ64A	SMCJ64CA	GGM	BGM	64.0	71.10	78.60	1	103.0	14.56	5
SMCJ70A	SMCJ70CA	GGP	BGP	70.0	77.80	86.00	1	113.0	13.27	5
SMCJ75A	SMCJ75CA	GGR	BGR	75.0	83.30	92.10	1	121.0	12.40	5
SMCJ78A	SMCJ78CA	GGT	BGT	78.0	86.70	95.80	1	126.0	11.90	5
SMCJ80A	SMCJ80CA	GGB	BGB	80.0	88.80	97.60	1	129.6	11.57	5
SMCJ85A	SMCJ85CA	GGV	BGV	85.0	94.40	104.00	1	137.0	10.95	5
SMCJ90A	SMCJ90CA	GGX	BGX	90.0	100.00	111.00	1	146.0	10.27	5
SMCJ100A	SMCJ100CA	GGZ	BGZ	100.0	111.00	123.00	1	162.0	9.26	5
SMCJ110A	SMCJ110CA	GHE	BHE	110.0	122.00	135.00	1	177.0	8.47	5
SMCJ120A	SMCJ120CA	GHG	BHG	120.0	133.00	147.00	1	193.0	7.77	5
SMCJ130A	SMCJ130CA	GHK	BHK	130.0	144.00	159.00	1	209.0	7.18	5
SMCJ140A	SMCJ140CA	GHB	BHB	140.0	155.00	171.00	1	226.8	6.61	5
SMCJ150A	SMCJ150CA	GHM	ВНМ	150.0	167.00	185.00	1	243.0	6.17	5
SMCJ160A	SMCJ160CA	GHP	BHP	160.0	178.00	197.00	1	259.0	5.79	5
SMCJ170A	SMCJ170CA	GHR	BHR	170.0	189.00	209.00	1	275.0	5.45	5
SMCJ180A	SMCJ180CA	GHT	BHT	180.0	201.00	220.00	1	291.6	5.14	5
SMCJ190A	SMCJ190CA	GHV	BHV	190.0	211.00	232.00	1	307.8	4.87	5
SMCJ200A	SMCJ200CA	GHW	BHW	200.0	224.00	247.00	1	324.0	4.60	5
SMCJ220A	SMCJ220CA	GHX	BHX	220.0	246.00	272.00	1	356.0	4.20	5
SMCJ250A	SMCJ250CA	GHZ	BHZ	250.0	279.00	309.00	1	405.0	3.70	5
SMCJ300A	SMCJ300CA	GJE	BJE	300.0	335.00	371.00	1	486.0	3.10	5
SMCJ350A	SMCJ350CA	GJG	BJG	350.0	391.00	432.00	1	567.0	2.60	5
SMCJ400A	SMCJ400CA	GJK	ВЈК	400.0	447.00	494.00	1	648.0	2.30	5
SMCJ440A	SMCJ440CA	GJM	ВЈМ	440.0	492.00	543.00	1	713.0	2.10	5

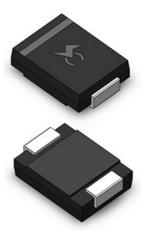
- Note:

  1. Suffix 'A' denotes 5% tolerance device.

  2. Add suffix 'CA' after part number to specify Bi-directional devices.

  3. For Bi-Directional devices having  $V_{\rm N}$  of 10 volts and under, the  $I_{\rm N}$  limit is double.









#### Description

The SMCJ series is designed specifically to protect sensitive electronic equipment from voltage transients induced by lightning and other transient voltage events.

#### **Features**

- For surface mounted applications in order to optimize board space
- Low leakage
- Uni and Bidirectional unit
- Glass passivated junction
- Low inductance
- Excellent clamping capability
- 1500W Peak power capability at 10 × 1000µs waveform Repetition rate (duty cycle):0.01%
- $\blacklozenge$  Fast response time: typically less than 1.0ps from 0 Volts to VBR min
- Typical I<sub>R</sub> less than 5μA above 12V.
- High Temperature soldering: 260°C/40 seconds at terminals
- Typical maximum temperature coefficient  $\Delta V_{BR} = 0.1\% \times V_{BR} @25^{\circ}C \times \Delta T$
- Plastic package has Underwriters Laboratory Flammability 94V-0
- Matte tin lead-free Plated
- Halogen free and RoHS compliant
- Typical failure mode is short from over-specified voltage or current
- Whisker test is conducted based on JEDEC JESD201A per its table 4a and 4c
- ♦ IEC-61000-4-2 ESD 15kV(Air), 8kV (Contact)
- ESD protection of data lines in accordance with IEC 61000-4-2 (IEC801-2)
- EFT protection of data lines in accordance with IEC 61000-4-4 (IEC801-4)

#### **Applications**

TVS devices are ideal for the protection of I/O interfaces, V<sub>CC</sub> bus and other vulnerable circuits used in Telecom, Computer, Industrial and Consumer electronic applications.

## **Functional Diagram** Bi-directional Cathode o-—○ Anode Uni-direction

Maximum Ratings (T <sub>A</sub> =25 <sup>U</sup> unless otherwise noted)			
Parameter	Symbol	Value	Unit
Peak Pulse Power Dissipation with a 10/1000µs waveform (Fig.1)(Note 1), (Note 2)	P <sub>PPM</sub>	1500	Watts
Peak Pulse Current with a 10/1000µs waveform.(Note1,Fig.3)	Ipp	See Next Table	Amps
Power Dissipation on Infinite Heat Sink at T <sub>L</sub> =75°C	P <sub>M(AV)</sub>	6.5	Watt
Peak Forward Surge Current, 8.3ms Single Half Sine Wave (Note 3)	IFSM	200	Amps
Maximum Instantaneous Forward Voltage at 25A for Unidirectional Only (Note 4)	VF	3.5/5.0	Voltage
Operating junction and Storage Temperature Range.	TJ, TSTG	-55 to +150	*C
Natara			

#### Notes:

- Non-repetitive current pulse, per Fig. 3 and derated above T<sub>A</sub> = 25°C per Fig. 2.
- 2. Mounted on 5.0mmx 5.0mm(0.03mmthick) Copper Pads to each terminal. 3.8.3ms single half sine-wave, or equivalent square wave, Duty cycle = 4 pulses per minutes maximum. 4.  $V_F < 3.5V$  for  $V_{SR} < 200V$  and  $V_F < 6.5V$  for  $V_{SR} > 201V$ .



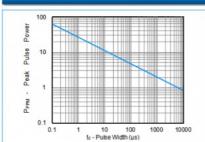




Figure 3 - Pulse Waveform

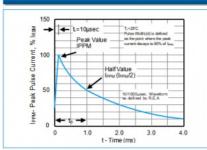


Figure 4 - Typical Junction Capacitance

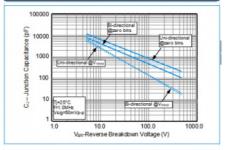


Figure 5 - Steady State Power Derating Curve

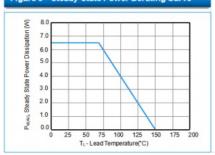
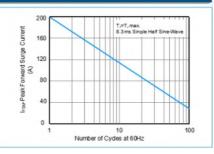
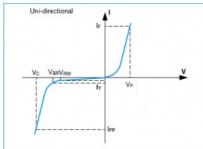


Figure 6 - Maximum Non-Repetitive Surge Current

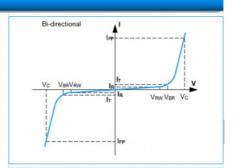


### I-V Curve Characteristics





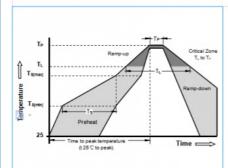
Weight	eight 0.007 ounce, 0.21 gram					
Case	JEDEC DO-214AB Molded Plastic over glass passivated junction					
Polarity	Color band denotes cathode except Bipolar					
Terminal	Matte Tin-plated leads, Solderable per JESD22-B102D					



#### **Environmental Specifications**

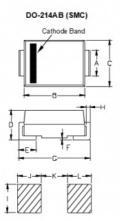
Temperature Cycle	JESD22-A104
Pressure Cooker	JESD22-A102
High Temp. Storage	JESD22-A103
HTRB	JESD22-A108
Thermal Shock	JESD22-A106

#### Soldering Parameters



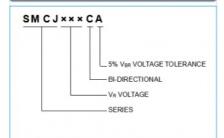
Reflow Co	ndition	Lead-free assembly	
	-Temperature Min (T <sub>s(min)</sub> )	150°C	
Pre Heat	-Temperature Max (T <sub>s(max)</sub> )	200°C	
	- Time (min to max) (T <sub>5</sub> )	60 -180 Seconds	
Average ra to peak	amp up rate ( Liquidus Temp T <sub>L</sub> )	3°C/second max	
T <sub>S(max)</sub> to T	L - Ramp-up Rate	3°C/second max	
Reflow	- Temperature (T <sub>L</sub> ) (Liquidus)	217°C	
Renow	- Time (min to max) (TL)	60 -150 Seconds	
Peak Temp	perature (T <sub>P</sub> )	260 +0/-5°C	
Time wi	thin 5°C of actual peak are (t <sub>p</sub> )	20 -40 Seconds	
Ramp-dow	rn Rate	6°C/second max	
Time 25°C	to peak Temperature (T <sub>P</sub> )	8 minutes Max	
Do not exc	eed	280°C	

#### Dimensions

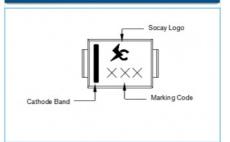


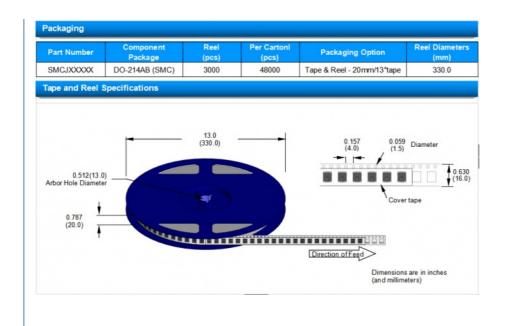
Dimensions	Inc	hes	Millimeters		
Dimensions	Min Max		Min	Max	
Α	0.108	0.126	2.750	3.200	
В	0.260	0.280	6.520	7.110	
С	0.217	0.244	5.520	6.220	
D	0.080	0.112	2.050	2.850	
E	0.030	0.060	0.750	1.520	
F	-	0.008	-	0.203	
G	0.305	0.320	7.640	8.130	
н	0.006	0.012	0.150	0.310	
1	0.121	-	3.070	-	
J	0.068	-	1.715	-	
К	-	0.185	-	4.690	
L	0.068	-	1.715	-	

### Part Numbering



### Part Marking







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